One Watt High Current PNP Transistor

Features

• This is a Pb-Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CE}	50	Vdc
Collector - Base Voltage	V _{CB}	50	Vdc
Emitter - Base Voltage	V _{EB}	5.0	Vdc
Collector Current - Continuous	Ic	2.0	Adc
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	900 5.0	mW mW/°C
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

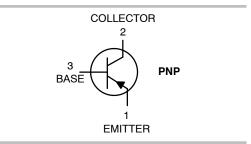
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

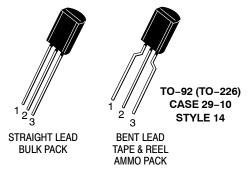


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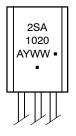
http://onsemi.com

VOLTAGE AND CURRENT ARE NEGATIVE FOR PNP TRANSISTORS





MARKING DIAGRAM



A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

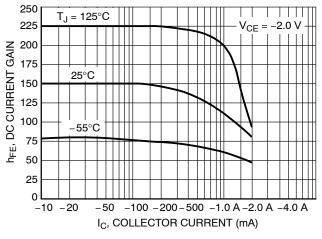
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·	•		
Collector – Emitter Breakdown Voltage (Note 1) (I _C = 10 mAdc, I _B = 0)	V _(BR) CEO	50	_	Vdc
Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0)	I _{CBO}	-	1.0	μAdc
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)	I _{EBO}	-	1.0	μAdc
ON CHARACTERISTICS (Note 2)	•			
DC Current Gain $(I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V})$ $(I_C = 1.5 \text{ A}, V_{CE} = 2.0 \text{ V})$	h _{FE}	70 40	240 _	_
Collector – Emitter Saturation Voltage (I _C = 1.0 A, I _B = 50 mA)	V _{CE(sat)}	-	0.5	Vdc
Base – Emitter Saturation Voltage (I _C = 1.0 A, I _B = 50 mA)	V _{BE(sat)}	_	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS	•	-	•	•
Current – Gain – Bandwidth Product (Note 3) (I _C = 500 mAdc, V _{CE} = 2.0 Vdc, f = 100 MHz)	f _T	100	_	MHz

ORDERING INFORMATION

Device	Package	Shipping [†]
2SA1020RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.
 Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.
 f_T is defined as the frequency at which |h_{fe}| extrapolates to unity.



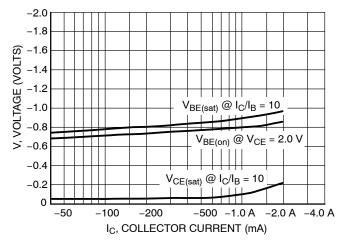


Figure 1. Typical DC Current Gain

Figure 2. On Voltages

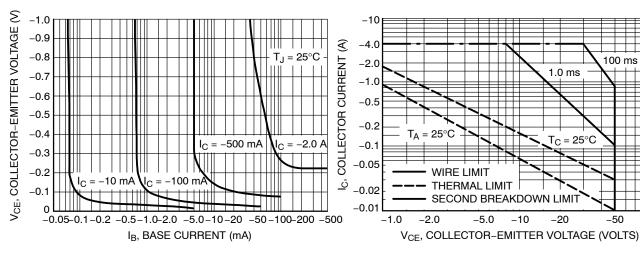


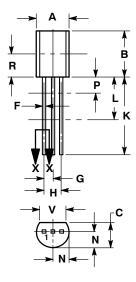
Figure 3. Collector Saturation Region

Figure 4. Safe Operating Area

-100

PACKAGE DIMENSIONS

TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE O**



STRAIGHT LEAD **BULK PACK**



NOTES

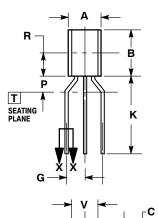
- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DI-MENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLE 14:

PIN 1. EMITTER COLLECTOR

BASE



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
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В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
V	0.135		3.43	

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